

IL205, IL206, IL207, IL208,
 IL211, IL212, IL213,
 IL215, IL216, IL217



**SMALL OUTLINE OPTICALLY
 COUPLED ISOLATOR
 TRANSISTOR OUTPUT**

DESCRIPTION

This series of optically coupled isolators consist of a Gallium Arsenide infrared emitting diode and NPN silicon photo transistor mounted in a standard 8 pin SOIC package, which makes them ideally suited for high density applications with limited space.

FEATURES

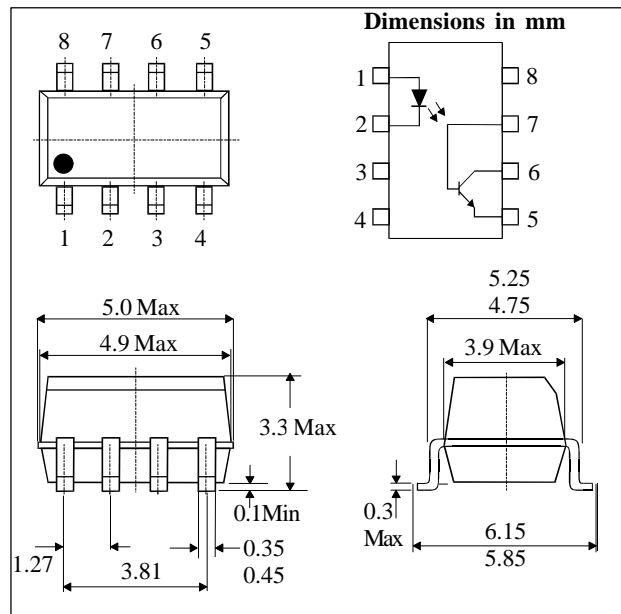
- Standard SOIC-8 Footprint with 0.05" Lead Spacing
- Specified min. and max. CTR at 10mA I_F, 5V V_{CE}
 IL205, 40 - 80%
 IL206, 63 - 125%
 IL207, 100 - 200%
 IL208, 160 - 320%
- Specified minimum CTR at 10mA I_F, 5V V_{CE}
 IL211, 20%
 IL212, 50%
 IL213, 100%
- Specified minimum CTR at 1mA I_F, 5V V_{CE}
 IL215, 20%
 IL216, 50%
 IL217, 100%
- Isolation Voltage, 2500 V_{RMS}
- High BV_{CEO} (70V min)
- All electrical parameters 100% tested
- Available in Tape and Reel - add suffix " T & R "
- Custom Electrical Selections available

**ABSOLUTE MAXIMUM RATINGS
 (25°C unless otherwise noted)**

Storage Temperature _____ -55°C to +125°C
 Operating Temperature _____ -55°C to +100°C
 Lead Soldering Temperature _____ 260°C
 (single wave for 10 secs)
 Input to Output Isolation Voltage _____ 2500V_{RMS}

INPUT DIODE

Forward D.C. Current _____ 60mA
 Reverse D.C. Voltage _____ 6V
 Peak Forward Current (tp ≤ 10µs) _____ 3A
 Power Dissipation _____ 100mW
 (derate linearly 1.33mW/°C above 25°C)
 Junction Temperature _____ 125°C



APPLICATIONS

- Computer Terminals
- Industrial Systems Controllers
- Hybrid substrates that require high density mounting
- Signal Transmission between systems of different potentials and impedances

OUTPUT TRANSISTOR

Collector-Emitter Voltage BV_{CEO} _____ 70V
 Emitter-Collector Voltage BV_{ECO} _____ 7V
 Collector -Base Voltage BV_{CBO} _____ 70V
 Collector Current _____ 50mA
 Collector Current _____ 100mA
 (pw ≤ 10ms , 50% duty ratio)
 Power Dissipation _____ 150mW
 (derate linearly 2.00mW/°C above 25°C)
 Junction Temperature _____ 125°C

PACKAGE

Total Power Dissipation _____ 250mW
 (derate linearly 3.3mW/°C above 25°C)

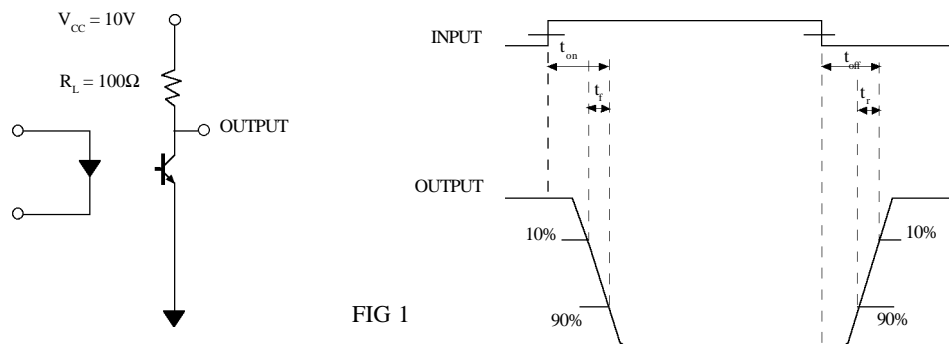
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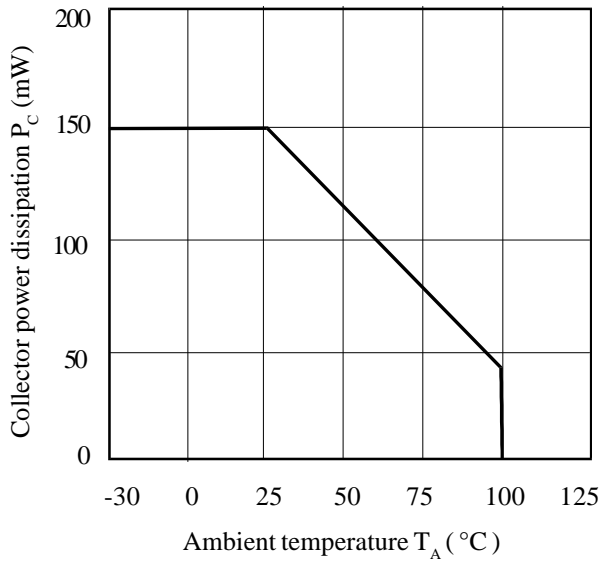
ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITIONS	
Input	Forward Voltage (V_F)		1.2	1.5	Volt	$I_F = 10 \text{ mA}$ $V_R = 0, f = 1 \text{ MHz}$ $V_R = 6 \text{ V}$	
	Capacitance		50		pF		
	Reverse Current (I_R)			100	μA		
Output	Collector-Emitter Voltage (BV_{CEO})	70			Volt	$I_C = 100 \mu\text{A}$ $I_E = 100 \mu\text{A}$ $I_C = 100 \mu\text{A}$ $V_{CE} = 10 \text{ V}$	
	Emitter-Collector Voltage (BV_{ECO})	7			Volt		
	Collector-Base Voltage (BV_{CBO})	70			Volt		
	Collector-Emitter Dark Current (I_{CEO})			50	nA		
Coupled	Current Transfer Ratio (CTR) IL205	40		80	%	$I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}$	
	IL206	63		125	%		
	IL207	100		200	%		
	IL208	160		320	%		
	IL211	20			%		
	IL212	50			%		
	IL213	100			%		
	IL205	13			%	$I_F = 1 \text{ mA}, V_{CE} = 5 \text{ V}$	
	IL206	22			%		
	IL207	34			%		
	IL208	56			%		
	IL215	20			%		
	IL216	50			%		
	IL217	100			%		
	Collector-Emitter Saturation Voltage $V_{CE(SAT)}$ (IL205 to IL213)				0.4	Volt	$I_F = 10 \text{ mA}, I_C = 2 \text{ mA}$
	Collector-Emitter Saturation Voltage $V_{CE(SAT)}$ (IL215 to IL217)				0.4	Volt	$I_F = 1 \text{ mA}, I_C = 0.1 \text{ mA}$
	Capacitance Input to Output (C_{IO})			0.3		pF	$f = 1 \text{ MHz}$ (note 1)
Input to Output Isolation Resistance (R_{IO})		10^{11}			Ω	$V_{IO} = 500 \text{ V}$ (note 1)	
Input to Output Isolation Voltage (V_{IO})	2500				V_{RMS}	Note 1	
Output Turn on Time (t_{on})			3.0		μs	$I_C = 2 \text{ mA},$ $V_{CC} = 10 \text{ V}, R_L = 100 \Omega$	
Output Turn off Time (t_{off})			3.0		μs		
Output Rise Time (t_r)			1.6		μs		
Output Fall Time (t_f)			2.2		μs		

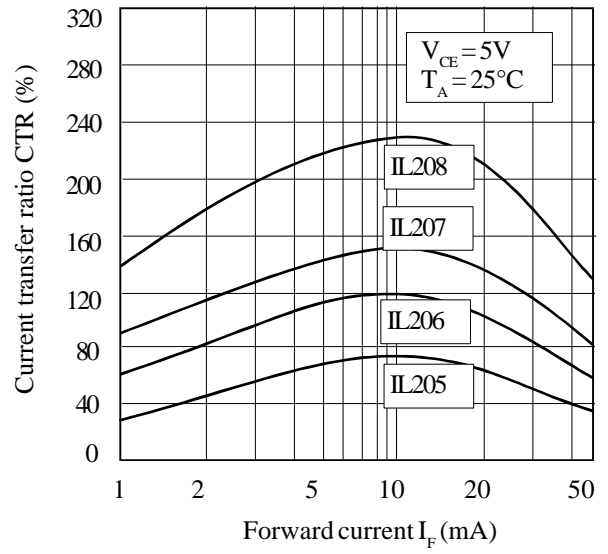
Note 1. Measured with input leads shorted together and output leads shorted together.



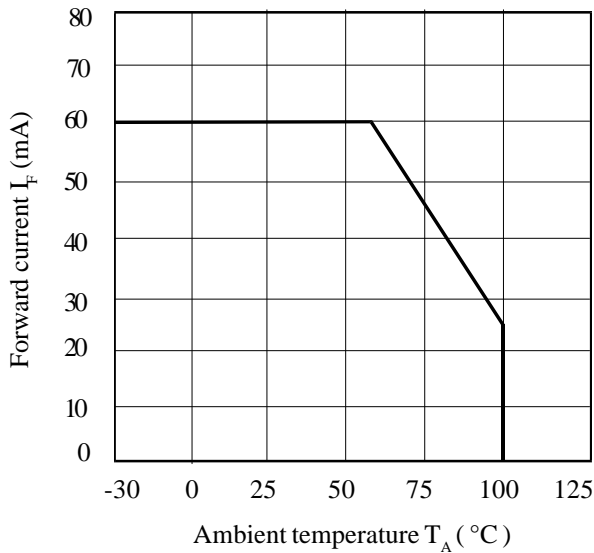
Collector Power Dissipation vs. Ambient Temperature



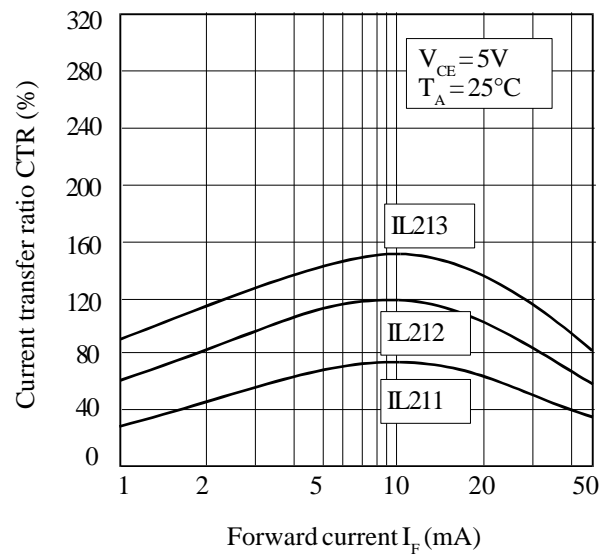
Current Transfer Ratio vs. Forward Current



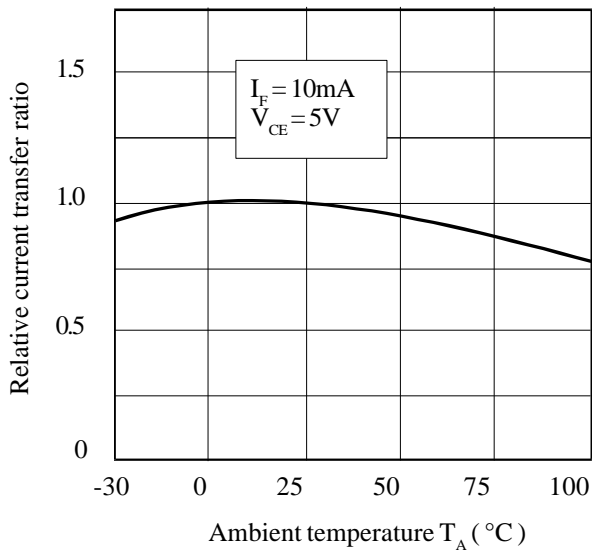
Forward Current vs. Ambient Temperature



Current Transfer Ratio vs. Forward Current



Relative Current Transfer Ratio vs. Ambient Temperature



Current Transfer Ratio vs. Forward Current

